## NSN 5962-01-381-9271

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View Online at https://aerobasegroup.com/nsn/5962-01-381-9271

Body Length:
0.440 inches
Body Width:
0.285 inches
Body Height:
0.085 inches
Maximum Power Dissipation Rating:
739.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
3-state output and schottky and bipolar and programmable and high impedance
Inclosure Material:
Ceramic
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
6 input
Case Outline Source And Designator:
F-5 mil-m-38510
Current Rating Per Characteristic:
130.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
80.00 nanoseconds propagation delay time, high to low level output and 80.00 nanoseconds propagation delay time, low to high level
output
Memory Device Type:
Prom
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain

environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## Terminal Type And Quantity:

16 flat leads

## **Specification Data:**

81349-mil-m-38510/207 government specification

Shelf Life:

N/a

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Demilitarization:

Yes - demil/mli

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